

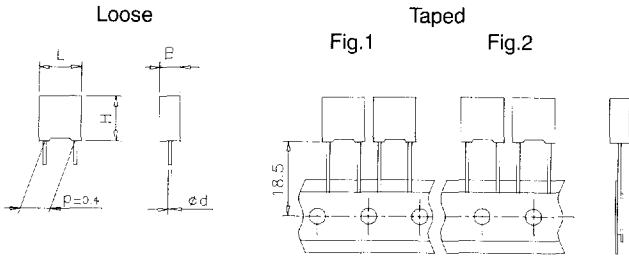
**METALLIZED POLYESTER FILM CAPACITOR
MINIATURE TYPE**

Typical applications: this series combines small size, good performances in by-passing, blocking and interference suppression in low voltage applications (i.e.: AUTOMOTIVE).

PRODUCT CODE: **R66** **p = 7.5 mm**

Note: R66 series has replaced the R84 series (available only upon request). For new design we suggest the use of the R66 series.

Construction:
STACKED and WOUND technology

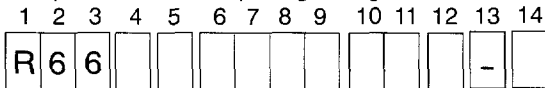


B max	2.5	≥3.5
∅ d ± 0.05	0.5	0.6

All dimensions are in mm

PRODUCT CODE SYSTEM

The part number, comprising 14 digits, is formed as follows:



- Digit 1 to 3 Series code.
- Digit 4 d.c. rated voltage:
D = 63V E = 100V I = 250V
M = 400V P = 630V
- Digit 5 Pitch: D = 7.5mm
- Digit 6 to 9 Digits 7 - 8 - 9 indicate the first three digits of Capacitance value and the 6th digit indicates the number of zeros that must be added to obtain the Rated Capacitance in pF.
- Digit 10 to 11 Mechanical version and/or packaging (table 1)
- Digit 12 Identifies the dimensions and electrical characteristics.
- Digit 13 Internal use
- Digit 14 Capacitance tolerance:
J=5%; K=10%; M=20%

GENERAL TECHNICAL DATA

- Dielectric:** polyester film (polyethylene terephthalate).
- Plates:** aluminium layer deposited by evaporation under vacuum.
- Winding:** non-inductive type.
- Leads:** tinned wire.
- Protection:** plastic case, thermosetting resin filled.
Box material is solvent resistant and flame retardant according to UL94 V0.
- Marking:** Manufacturer's logo, capacitance, tolerance, D.C. rated voltage.
- Climatic category:** 55/100/56 IEC 60068-1
- Operating temperature range:** -55 to +105°C
For stacked technology an upper operating temperature of +125°C is allowed for a max operating time of 1000h.
- Related documents:** IEC 60384-2

Winding scheme

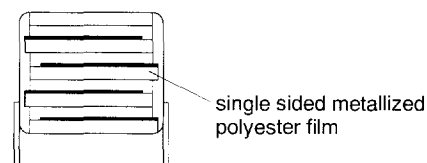


Table 1 (for more detailed information, please refer to page 15).

Standard packaging style	Lead length (mm)	Taping style Figure No.	Ordering code (Digit 10 to 11)
AMMO-PACK		1	DQ
AMMO-PACK		2	28
REEL ∅ 355mm		1	CK
Loose, short leads	4 +2		AA
Loose, long leads	17 +1/-2		Z3

Note: Ammo-pack is the preferred packaging for taped version.

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NEW

STACKED VERSION

Rated Cap.	63Vdc/40Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.33μF	2.5	7.0	10.0	7.5	120	15 E3	R66DD3330--6--
0.47μF	3.0	8.0	10.0	7.5	120	15 E3	R66DD3470--6--
0.68μF	3.5	8.5	10.5	7.5	120	15 E3	R66DD3680--6--
1.0μF	4.0	9.0	10.5	7.5	120	15 E3	R66DD4100--6--
1.5μF	5.0	11.0	10.5	7.5	120	15 E3	R66DD4150--6--
2.2μF	6.0	12.0	10.5	7.5	120	15 E3	R66DD4220--6--
3.3μF	6.0	12.0	10.5	7.5	120	15 E3	R66DD4330--6--

Rated Cap.	400Vdc/200Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
6800pF	2.5	7.0	10.0	7.5	275	220 E3	R66MD1680--6--
0.010μF	2.5	7.0	10.0	7.5	275	220 E3	R66MD2100--6--
0.015μF	2.5	7.0	10.0	7.5	275	220 E3	R66MD2150--6--
0.022μF	3.0	8.0	10.0	7.5	275	220 E3	R66MD2220--6--
0.033μF	3.5	8.5	10.5	7.5	275	220 E3	R66MD2330--6--
0.047μF	4.0	9.0	10.5	7.5	275	220 E3	R66MD2470--6--
0.068μF	5.0	11.0	10.5	7.5	275	220 E3	R66MD2680--6--
0.10μF	6.0	12.0	10.5	7.5	275	220 E3	R66MD3100--6--
0.15μF	6.0	12.0	10.5	7.5	275	220 E3	R66MD3150--6--

Rated Cap.	100Vdc/63Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.068μF	2.5	7.0	10.0	7.5	150	30 E3	R66ED2680--6--
0.10μF	2.5	7.0	10.0	7.5	150	30 E3	R66ED3100--6--
0.15μF	2.5	7.0	10.0	7.5	150	30 E3	R66ED3150--6--
0.22μF	2.5	7.0	10.0	7.5	150	30 E3	R66ED3220--6--
0.33μF	3.5	8.5	10.5	7.5	150	30 E3	R66ED3330--6--
0.47μF	3.5	8.5	10.5	7.5	150	30 E3	R66ED3470--6--
0.68μF	4.0	9.0	10.5	7.5	150	30 E3	R66ED3680--6--
1.0μF	5.0	11.0	10.5	7.5	150	30 E3	R66ED4100--6--
1.5μF	6.0	12.0	10.5	7.5	150	30 E3	R66ED4150--6--

Rated Cap.	630Vdc/220Vac*				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number	
	B	H	L	p				
1000pF	2.5	7.0	10.0	7.5	300	378 E3	In Progress	
1500pF	2.5	7.0	10.0	7.5	300	378 E3		
2200pF	2.5	7.0	10.0	7.5	300	378 E3		
3300pF	2.5	7.0	10.0	7.5	300	378 E3		
4700pF	2.5	7.0	10.0	7.5	300	378 E3		
6800pF	3.0	8.0	10.0	7.5	300	378 E3		
0.010μF	3.5	8.5	10.5	7.5	300	378 E3		
0.015μF	4.0	9.0	10.5	7.5	300	378 E3		
0.022μF	5.0	11.0	10.5	7.5	300	378 E3		
0.033μF	6.0	12.0	10.5	7.5	300	378 E3		
0.047μF	6.0	12.0	10.5	7.5	300	378 E3		
								R66PD2100--6--
								R66PD2150--6--
								R66PD2220--6--
								R66PD2330--6--
								R66PD2470--6--

Rated Cap.	250Vdc/160Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.022μF	2.5	7.0	10.0	7.5	200	100 E3	R66ID2220--6--
0.033μF	2.5	7.0	10.0	7.5	200	100 E3	R66ID2330--6--
0.047μF	2.5	7.0	10.0	7.5	200	100 E3	R66ID2470--6--
0.068μF	3.0	8.0	10.0	7.5	200	100 E3	R66ID2680--6--
0.10μF	3.5	8.5	10.5	7.5	200	100 E3	R66ID3100--6--
0.15μF	4.0	9.0	10.5	7.5	200	100 E3	R66ID3150--6--
0.22μF	5.0	11.0	10.5	7.5	200	100 E3	R66ID3220--6--
0.33μF	6.0	12.0	10.5	7.5	200	100 E3	R66ID3330--6--

Mechanical version and packaging (Table 1)

Internal use

Tolerance: J (± 5%); K (± 10%); M (± 20%)

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All dimensions are in mm.

Note: If the working voltage (V) is lower than the rated voltage (V_R), the capacitor may work at higher dv/dt. In this case the maximum value allowed is obtained multiplying the above value (see table dv/dt) with the ratio V_R/V.
The pulse characteristic K₀ depends on the voltage wave-form and in any case it cannot overcome the value given in the above table.

* Not suitable for across-the-line applications. Please refer to Interference Suppression Capacitors (page 109).

**METALLIZED POLYESTER FILM CAPACITOR
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p = 7.5 mm

PRODUCT CODE: R66

WOUND VERSION

Rated Cap.	63Vdc/40Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.10μF	2.5	7.0	10.0	7.5	5	0.63 E3	R66DD3100--0--
0.15μF	2.5	7.0	10.0	7.5	5	0.63 E3	R66DD3150--0--
0.22μF	3.5	8.5	10.5	7.5	5	0.63 E3	R66DD3220--0--
0.33μF	3.5	8.5	10.5	7.5	5	0.63 E3	R66DD3330--0--
0.47μF	4.0	9.0	10.5	7.5	5	0.63 E3	R66DD3470--0--
0.68μF	5.0	11.0	10.5	7.5	5	0.63 E3	R66DD3680--0--
1.0μF	6.0	12.0	10.5	7.5	5	0.63 E3	R66DD4100--0--

Rated Cap.	400Vdc/200Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
3300pF	2.5	7.0	10.0	7.5	30	24 E3	R66MD1330--0--
4700pF	2.5	7.0	10.0	7.5	30	24 E3	R66MD1470--0--
6800pF	2.5	7.0	10.0	7.5	30	24 E3	R66MD1680--0--
0.010μF	2.5	7.0	10.0	7.5	30	24 E3	R66MD2100--0--
0.015μF	3.5	8.5	10.5	7.5	30	24 E3	R66MD2150--0--
0.022μF	3.5	8.5	10.5	7.5	30	24 E3	R66MD2220--0--
0.033μF	4.0	9.0	10.5	7.5	30	24 E3	R66MD2330--0--
0.047μF	5.0	11.0	10.5	7.5	30	24 E3	R66MD2470--0--
0.068μF	5.0	11.0	10.5	7.5	30	24 E3	R66MD2680--0--
0.10μF	6.0	12.0	10.5	7.5	30	24 E3	R66MD3100--0--

Rated Cap.	100Vdc/63Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.047μF	2.5	7.0	10.0	7.5	6	1.2 E3	R66ED 2470--0--
0.068μF	2.5	7.0	10.0	7.5	6	1.2 E3	R66ED 2680--0--
0.10μF	3.5	8.5	10.5	7.5	6	1.2 E3	R66ED 3100--0--
0.15μF	3.5	8.5	10.5	7.5	6	1.2 E3	R66ED 3150--0--
0.22μF	3.5	8.5	10.5	7.5	6	1.2 E3	R66ED 3220--0--
0.33μF	5.0	11.0	10.5	7.5	6	1.2 E3	R66ED 3330--0--
0.47μF	6.0	12.0	10.5	7.5	6	1.2 E3	R66ED 3470--0--

Rated Cap.	630Vdc/220Vac*				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
1000pF	2.5	7.0	10.0	7.5	40	50 E3	R66PD 1100--0--
1500pF	2.5	7.0	10.0	7.5	40	50 E3	R66PD 1150--0--
2200pF	2.5	7.0	10.0	7.5	40	50 E3	R66PD 1220--0--
3300pF	3.5	8.5	10.5	7.5	40	50 E3	R66PD 1330--0--
4700pF	3.5	8.5	10.5	7.5	40	50 E3	R66PD 1470--0--
6800pF	3.5	8.5	10.5	7.5	40	50 E3	R66PD 1680--0--
0.010μF	4.0	9.0	10.5	7.5	40	50 E3	R66PD 2100--0--
0.015μF	5.0	11.0	10.5	7.5	40	50 E3	R66PD 2150--0--
0.022μF	6.0	12.0	10.5	7.5	40	50 E3	R66PD 2220--0--

Rated Cap.	250Vdc/160Vac				Max dv/dt (V/μs)	Max K ₀ (V ² /μs)	Part Number
	B	H	L	p			
0.015μF	2.5	7.0	10.0	7.5	15	7.5 E3	R66ID 2150--0--
0.022μF	2.5	7.0	10.0	7.5	15	7.5 E3	R66ID 2220--0--
0.033μF	2.5	7.0	10.0	7.5	15	7.5 E3	R66ID 2330--0--
0.047μF	3.5	8.5	10.5	7.5	15	7.5 E3	R66ID 2470--0--
0.068μF	3.5	8.5	10.5	7.5	15	7.5 E3	R66ID 2680--0--
0.10μF	4.0	9.0	10.5	7.5	15	7.5 E3	R66ID 3100--0--
0.15μF	5.0	11.0	10.5	7.5	15	7.5 E3	R66ID 3150--0--
0.22μF	6.0	12.0	10.5	7.5	15	7.5 E3	R66ID 3220--0--

Mechanical version and packaging (Table 1)

Internal use

Tolerance: J (± 5%); K (± 10%); M (± 20%)

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Internal use

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All dimensions are in mm.

Note: If the working voltage (V) is lower than the rated voltage (V_R), the capacitor may work at higher dv/dt. In this case the maximum value allowed is obtained multiplying the above value (see table dv/dt) with the ratio V_R/V.
The pulse characteristic K₀ depends on the voltage wave-form and in any case it cannot overcome the value given in the above table.

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**METALLIZED POLYESTER FILM CAPACITOR
MINIATURE TYPE**

p = 7.5 mm

PRODUCT CODE: R66

ELECTRICAL CHARACTERISTICS

Rated voltage (V_R): 63 Vdc - 100 Vdc - 250 Vdc
400 Vdc - 630 Vdc

Rated temperature (T_R): +85°C

Temperature derated voltage:

for temperatures between +85°C and the upper operating temperature (+105°C for wound technology and +125°C for stacked technology) a decreasing factor of 1.25% per degree °C on the rated voltage V_R has to be applied.

Capacitance range: 1000pF to 3.3µF

Capacitance values:

E6 series (IEC 60063 Norm).

Capacitance tolerances (measured at 1 kHz):

± 5% (J); ± 10% (K); ± 20% (M).

Total self-inductance (L): ≈ 8nH

(lead length ~2mm)

Dissipation factor (DF):

tgδ × 10⁻⁴. at +25°C ± 5°C

kHz	tgδ × 10 ⁻⁴
1	≤ 100
10	≤ 150

Insulation resistance:

Test conditions

Temperature: +25°C ± 5°C

Voltage charge time: 1 min

Voltage charge: 50 Vdc for V_R < 100 Vdc
100 Vdc for V_R ≥ 100 Vdc

Performance

For V_R ≤ 100 Vdc

≥ 3750 MΩ for C ≤ 0.33µF (5000 MΩ)*

≥ 1250 s for C > 0.33µF (5000 s)*

For V_R > 100 Vdc

≥ 30000MΩ (50000 MΩ)*

*Typical value

Test voltage between terminals:

1.6 × V_R applied for 2 s at +25°C ± 5°C

TEST METHOD AND PERFORMANCE

Damp heat, steady state:

Test conditions

Temperature: +40°C ± 2°C

Relative humidity (RH): 93% ± 2%

Test duration: 56 days

Performance

Capacitance change |ΔC/C|: ≤ 5%

DF change (Δtgδ): ≤ 50 × 10⁻⁴ at 1kHz

Insulation resistance: ≥ 50% of initial limit.

Endurance:

Test conditions

Temperature: +100°C ± 2°C

Test duration: 2000 h

Voltage applied: 1.25 × V_C

Performance

Capacitance change |ΔC/C|: ≤ 5%

DF change (Δtgδ): ≤ 50 × 10⁻⁴ at 10kHz

Insulation resistance: ≥ 50% of initial limit.

Resistance to soldering heat:

Test conditions

Solder bath temperature: +260°C ± 5°C

Dipping time (with heat screen): 10 s ± 1 s

Performance

Capacitance change |ΔC/C|: ≤ 2%

DF change (Δtgδ): ≤ 50 × 10⁻⁴ at 10kHz

Insulation resistance: ≥ initial limit.

Long term stability (after two years):

Storage

standard environmental conditions (see page 11).

Performance

Capacitance change |ΔC/C|: ≤ 3% for C ≤ 0.1µF
≤ 2% for C > 0.1µF

RELIABILITY

Reference MIL HDB 217

Application conditions:

Temperature: +40°C ± 2°C

Voltage: 0.5 × V_R

Failure rate: ≤ 2 FIT

(1 FIT = 1 × 10⁻⁹ failures/components × h)

Failure criteria:

(according to DIN 44122)

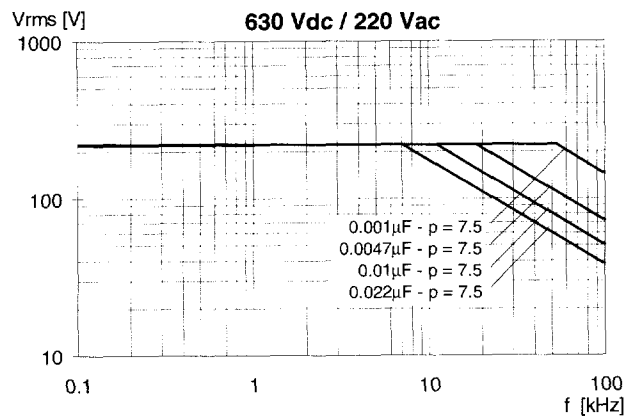
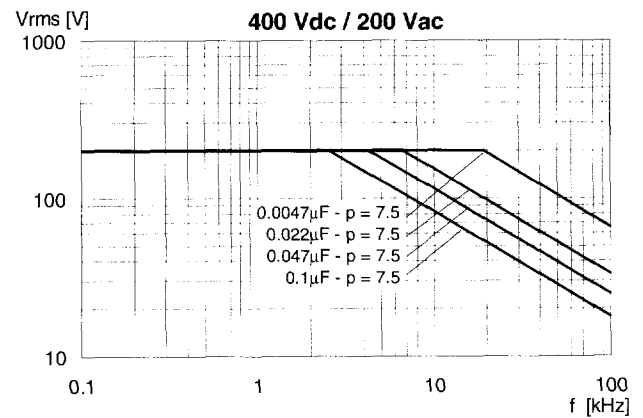
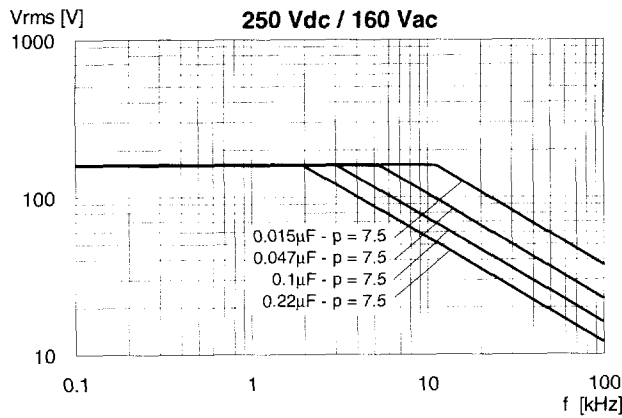
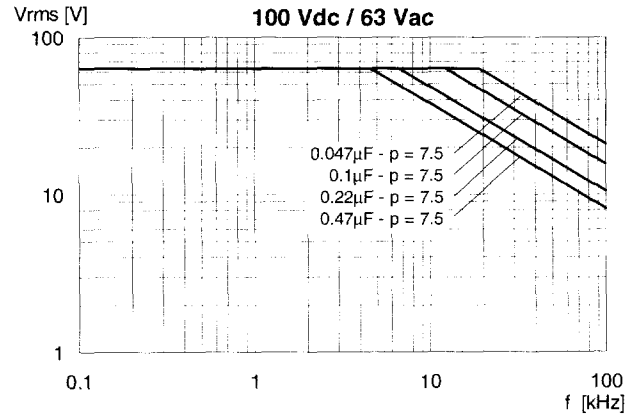
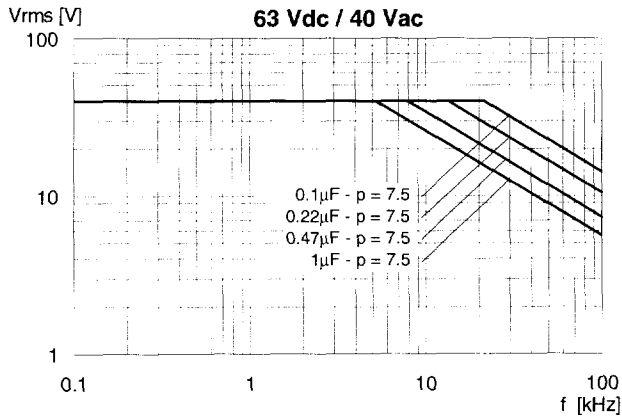
Short or open circuit

Capacitance change |ΔC/C|: > 10%

DF change (Δtgδ): > 2 × initial limit.

Insulation resistance: < 0.005 × initial limit.

MAX. VOLTAGE (Vr.m.s.) VERSUS FREQUENCY (sinusoidal wave-form / $T_h \leq 40^\circ\text{C}$)



Note: p (pitch) in mm.